2N3906

General Purpose Transistors

PNP Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|-------------|-------------|
| Collector - Emitter Voltage | V _{CEO} | 40 | Vdc |
| Collector - Base Voltage | V _{CBO} | 40 | Vdc |
| Emitter – Base Voltage | V _{EBO} | 5.0 | Vdc |
| Collector Current - Continuous | I _C | 200 | mAdc |
| Total Device Dissipation @ T _A = 25°C Derate above 25°C | P _D | 625 5.0 | mW mW/°C |
| Total Power Dissipation @ T _A = 60°C | P _D | 250 | mW |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | P _D | 1.5 12 | W mW/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

THERMAL CHARACTERISTICS (Note 1)

| Characteristic | Symbol | Max | Unit |
|---|-----------------|------|------|
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 200 | °C/W |
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 83.3 | °C/W |

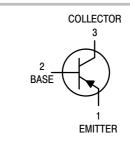
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

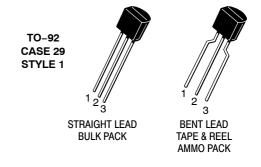
1. Indicates Data in addition to JEDEC Requirements.



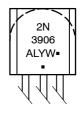
ON Semiconductor®

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MARKING DIAGRAM



A = Assembly Location

= Wafer Lot

Y = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

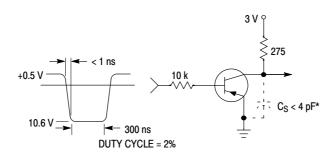
| | Character | Symbol | Min | Max | Unit | |
|---|---|--|----------------------|-----------------------------|--------------------|--------------------|
| OFF CHARACTERIS | TICS | | | | • | |
| Collector - Emitter Br | eakdown Voltage (Note 2) | $(I_C = 1.0 \text{ mAdc}, I_B = 0)$ | V _{(BR)CEO} | 40 | - | Vdc |
| Collector - Base Brea | kdown Voltage | $(I_C = 10 \mu Adc, I_E = 0)$ | V _{(BR)CBO} | 40 | - | Vdc |
| Emitter - Base Break | down Voltage | $(I_E = 10 \mu Adc, I_C = 0)$ | V _{(BR)EBO} | 5.0 | _ | Vdc |
| Base Cutoff Current | | (V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc) | I _{BL} | - | 50 | nAdc |
| Collector Cutoff Curre | ent | (V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc) | I _{CEX} | - | 50 | nAdc |
| ON CHARACTERIST | TICS (Note 2) | | | • | | - |
| | | $(I_C = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$ | h _{FE} | 60 80 100 60 30 | - 300 - - | _ |
| Collector – Emitter Saturation Voltage | | | V _{CE(sat)} | - - | 0.25 0.4 | Vdc |
| Base – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}$, $I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}$, $I_B = 5.0 \text{ mAdc}$) | | V _{BE(sat)} | 0.65 - | 0.85 0.95 | Vdc | |
| SMALL-SIGNAL CH | IARACTERISTICS | | | | | |
| Current-Gain - Ban | dwidth Product (I _C | = 10 mAdc, V _{CE} = 20 Vdc, f = 100 MHz) | f _T | 250 | - | MHz |
| Output Capacitance | | (V _{CB} = 5.0 Vdc, I _E = 0, f = 1.0 MHz) | C _{obo} | - | 4.5 | pF |
| Input Capacitance | | (V _{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz) | C _{ibo} | - | 10 | pF |
| Input Impedance | (I _C | = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz) | h _{ie} | 2.0 | 12 | kΩ |
| Voltage Feedback Ra | atio (I _C | = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz) | h _{re} | 0.1 | 10 | X 10 ⁻⁴ |
| Small-Signal Current | Gain (I _C | = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz) | h _{fe} | 100 | 400 | - |
| Output Admittance ($I_C = 1.0 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, $f = 1.0 \text{ kHz}$) | | h _{oe} | 3.0 | 60 | μmhos | |
| Noise Figure | (I _C = 100 μAdc, \ | $V_{CE} = 5.0 \text{ Vdc}, R_S = 1.0 \text{ k}\Omega, f = 1.0 \text{ kHz}$ | NF | - | 4.0 | dB |
| SWITCHING CHARA | CTERISTICS | | | | | |
| Delay Time $(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc},$ | | t _d | - | 35 | ns | |
| Rise Time | $I_C = 10 \text{ mAdc}, I_{B1} = 1.0$ | | t _r | - | 35 | ns |
| Storage Time | (V _{CC} = 3.0 Vdc, I _C = 10 | 0 mAdc, I _{B1} = I _{B2} = 1.0 mAdc) | t _s | - | 225 | ns |
| Fall Time | (V _{CC} = 3.0 Vdc, I _C = 10 | 0 mAdc, I _{B1} = I _{B2} = 1.0 mAdc) | t _f | - | 75 | ns |

^{2.} Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2%.

ORDERING INFORMATION

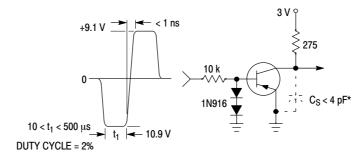
| Device | Package | Shipping [†] |
|-------------|--------------------|------------------------|
| 2N3906 | TO-92 | 5000 Units / Bulk |
| 2N3906G | TO-92 (Pb-Free) | 5000 Units / Bulk |
| 2N3906RL1 | TO-92 | 2000 / Tape & Reel |
| 2N3906RL1G | TO-92 (Pb-Free) | 2000 / Tape & Reel |
| 2N3906RLRA | TO-92 | 2000 / Tape & Reel |
| 2N3906RLRAG | TO-92 (Pb-Free) | 2000 / Tape & Reel |
| 2N3906RLRM | TO-92 | 2000 / Tape & Ammo Box |
| 2N3906RLRMG | TO-92 (Pb-Free) | 2000 / Tape & Ammo Box |
| 2N3906RLRP | TO-92 | 2000 / Tape & Ammo Box |
| 2N3906RLRPG | TO-92 (Pb-Free) | 2000 / Tape & Ammo Box |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



^{*} Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit

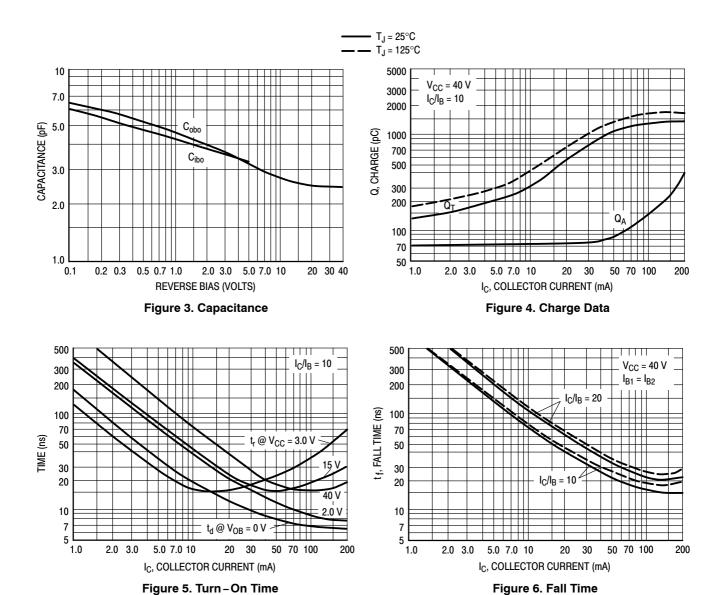


^{*} Total shunt capacitance of test jig and connectors

Figure 2. Storage and Fall Time Equivalent Test Circuit

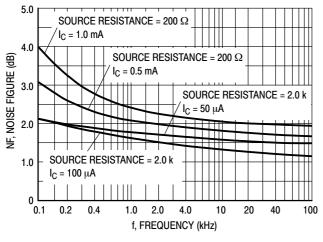
2N3906

TYPICAL TRANSIENT CHARACTERISTICS



TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$



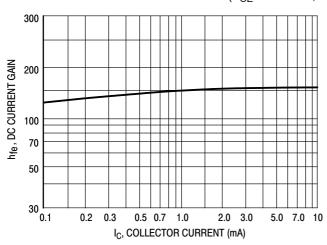
12 f = 1.0 kHz10 NF, NOISE FIGURE (dB) I_C = 50 μ A $I_C = 100 \mu A$ 0.2 2.0 4.0 0.4 1.0 10 20 40 0.1 100 R_q, SOURCE RESISTANCE (k OHMS)

Figure 7.

Figure 8.

h PARAMETERS

 $(V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$



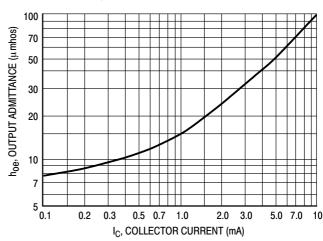
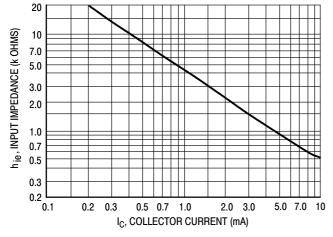


Figure 9. Current Gain

Current Gain Figure 10. Output Admittance



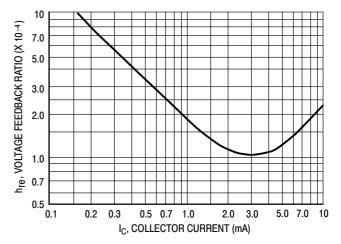


Figure 11. Input Impedance

Figure 12. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

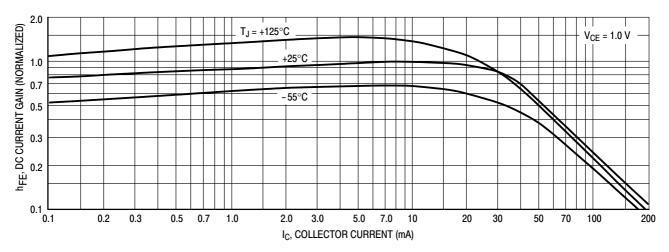


Figure 13. DC Current Gain

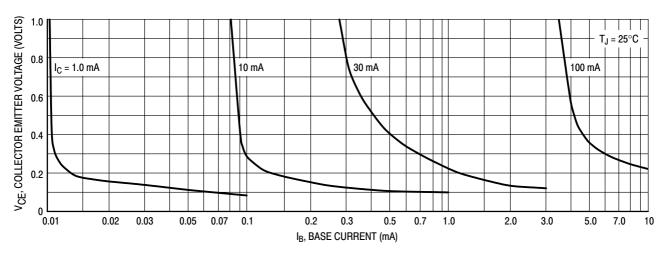


Figure 14. Collector Saturation Region

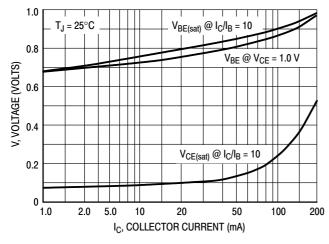


Figure 15. "ON" Voltages

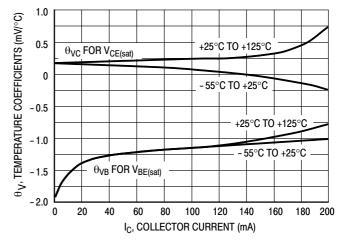
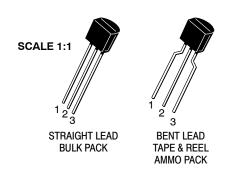


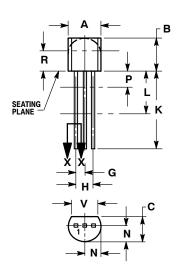
Figure 16. Temperature Coefficients





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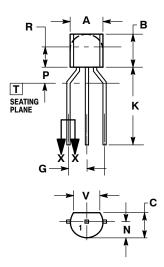


STRAIGHT LEAD **BULK PACK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | INC | HES | MILLIN | IETERS |
|-----|-------|-------|--------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.175 | 0.205 | 4.45 | 5.20 |
| В | 0.170 | 0.210 | 4.32 | 5.33 |
| С | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.021 | 0.407 | 0.533 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| Н | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | | 12.70 | |
| L | 0.250 | | 6.35 | |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | | 0.100 | | 2.54 |
| R | 0.115 | | 2.93 | |
| ٧ | 0.135 | | 3.43 | |



BENT LEAD TAPE & REEL AMMO PACK



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | MILLIMETERS | | | | |
|-----|-------------|------|--|--|--|
| DIM | MIN | MAX | | | |
| Α | 4.45 | 5.20 | | | |
| В | 4.32 | 5.33 | | | |
| С | 3.18 | 4.19 | | | |
| D | 0.40 | 0.54 | | | |
| G | 2.40 | 2.80 | | | |
| J | 0.39 | 0.50 | | | |
| K | 12.70 | | | | |
| N | 2.04 | 2.66 | | | |
| P | 1.50 | 4.00 | | | |
| R | 2.93 | | | | |
| V | 3.43 | | | | |

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| STYLE 1: PIN 1. 2. 3. | EMITTER BASE COLLECTOR | STYLE 2: PIN 1. 2. 3. | BASE EMITTER COLLECTOR | STYLE 3: PIN 1. 2. 3. | ANODE ANODE CATHODE | STYLE 4: PIN 1. 2. 3. | CATHODE CATHODE ANODE | STYLE 5: PIN 1. 2. 3. | DRAIN |
|--------------------------------|-------------------------------------|---------------------------------|--|---------------------------------|-------------------------------------|---------------------------------|---------------------------------------|---------------------------------|---------------|
| 2. | GATE SOURCE & SUBSTRATE DRAIN | STYLE 7: PIN 1. 2. 3. | SOURCE DRAIN GATE | STYLE 8: PIN 1. 2. 3. | DRAIN GATE SOURCE & SUBSTRATE | PIN 1. | BASE 1 | | CATHODE |
| 2. | ANODE CATHODE & ANODE CATHODE | STYLE 12: PIN 1. 2. 3. | MAIN TERMINAL 1 GATE MAIN TERMINAL 2 | PIN 1. | ANODE 1 | PIN 1. | EMITTER COLLECTOR BASE | PIN 1. 2. | |
| 2. | ANODE GATE | PIN 1. 2. | COLLECTOR BASE | PIN 1. 2. | ANODE CATHODE | PIN 1. 2. | GATE | 2. | NOT CONNECTED |
| 2. | COLLECTOR | PIN 1. 2. | SOURCE GATE DRAIN | STYLE 23: PIN 1. 2. 3. | GATE SOURCE DRAIN | STYLE 24: PIN 1. 2. 3. | EMITTER COLLECTOR/ANODE CATHODE | STYLE 25: PIN 1. 2. 3. | MT 1 GATE |
| | V _{CC} | PIN 1. 2. | MT | STYLE 28: PIN 1. 2. | CATHODE ANODE GATE | STYLE 29: PIN 1. 2. | | PIN 1. 2. | DRAIN |
| | GATE | PIN 1. 2. | | STYLE 33: PIN 1. 2. 3. | RETURN | 2. | | | |

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